








	<h2>SI1308EDL-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI1308EDL-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 1.4A SOT323</p> <p><b>Datenblätter:</b>  <a href="#">SI1308EDL-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 81619 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI1308EDL-T1-GE3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET N-CH 30V 1.4A SOT323
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	81619 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-70, SOT-323
Supplier Device-Gehäuse	SOT-323
Verlustleistung (max)	400mW (Ta), 500mW (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	1.4A (Tc)
Rds On (Max) @ Id, Vgs	132 mOhm @ 1.4A, 10V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	4.1nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	105pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)









SI1308EDL-T1-GE3 ist neu im Original, Suche SI1308EDL-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1308EDL-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1308EDL-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI1315DL-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 8V 0.9A SC70-3</p>	 <p><b>SI1308EDL</b> VB SI1308EDL VB</p>	 <p><b>SI13132CNU</b> SILICON SI13132CNU SILICON</p>	 <p><b>SI1307EDL-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 12V 0.85A SC-70-3</p>
 <p><b>SI1308EDL-T1-E3</b> Son SI1308EDL-T1-E3 Son</p>	 <p><b>SI1315DL-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 8V 0.9A SC70-3</p>	 <p><b>SI1308EDL-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 1.4A SOT323</p>	 <p><b>SI1307EDL-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 12V 0.85A SC-70-3</p>

### heiße Teile

Mehr

 SI1305DL-T1-E3	 SI1305DL-T1-GE3	 SI1305DL-T1-GE3	 SI1305DL-T1-E3	 SI1305EDL
 SI1305EDL-T1-E3	 SI1305EDL-T1-E3	 SI1305EDL-T1-GE3	 SI1305EDL-T1-GE3	 SI1305LT-T1-E3
 SI1306DL	 SI1307-DL-T1-E3	 SI1307DL	 SI1307DL-T1	 SI1307DL-T1-E3
 SI1307DL-T1-E3	 SI1307DL-T1-GE3	 SI1307DL-T1-GE3	 SI1307EDL	 SI1307EDL-T1-E3
 SI1307EDL-T1-E3	 SI1307EDL-T1-GE3	 SI1307EDL-T1-GE3	 SI1308EDL	 SI1308EDL-T1-GE3
 SI13132CNU	 SI1315DL-T1-GE3	 SI1315DL-T1-GE3	 SI1317DL-T1-GE3	 SI1317DL-T1-GE3
 SI1330EDL-T1-E3	 SI1330EDL-T1-E3	 SI1330EDL-T1-GE3	 SI1330EDL-T1-GE3	 SI1400DL-T1
 SI1400DL-T1-E3	 SI1400DL-T1-E3	 SI1400DL-T1-GE3	 SI1400DL-T1-GE3	 SI1401EDH-T1-GE3
 SI1401EDH-T1-GE3	 SI1402DH-T1-GE3	 SI1402DH-T1-GE3	 SI1403BDL-T1-E3	 SI1403BDL-T1-E3
 SI1403BDL-T1-GE3	 SI1403BDL-T1-GE3	 SI1403CDL-T1-GE3	 SI1403CDL-T1-GE3	 SI1403DL

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited